

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

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Title of Invention

METHOD OF FORMING STRAINED SILICON ON INSULATOR

Application Number :

10/605 408

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First Named Applicant:

Kern Rim

Attorney Docket Number:

YOR920000707US2

Art Unit:

Examiner:

Search string:

(5659187 or 5906951 or 6059895 or 6023082 or 6080235 or 5963817 or 6310367 or 6339232 or 5006913 or 5240876 or 6603156).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
1	1	5659187	1997-08-19	Legoues, et al		257	190
2	2	5906951	1999-05-22	Chu, et al		438	751
3	3	6059895	2000-05-09	Chu, et al		148	33.1
4	4	6023082	2000-02-08	McKee, et al		257	295
5	5	6080235	2000-06-27	McKee, et al		117	2
6	6	5963817	1999-10-05	Chu, et at		438	410
7	7	6310367	2001-10-30	Yagishita et al		257	190
8	8	6339232	2002-01-15	Takagi		257	192
9	9	5006913	1991-04-09	Sugahara, et al		357	41
10	10	5240876	1983-08-31	Gaul, et al		437	131
11	11	6603156	2003-08-05	Rim		257	190

Signature

Examiner Name

Date

Ex. M. H. H.

2/2/05